NSN 5961-01-272-1466

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-272-1466

Inclosure Material:

Metal

Overall Diameter:

Between 0.016 inches and 0.019 inches

Mounting Facility Quantity:

3

Mounting Method:

Terminal

Terminal Circle Diameter:

Between 0.199 inches and 0.201 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

800.00 milliamperes base current, dc blank

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-emitter absolute and 0.8 watts large-signal output power, common-base absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Extended lead length; junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0